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Vishay Semiconductor/Diodes Division VS-100BGQ030HF4

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-100BGQ030HF4 - DIODE SCHOTTKY 30V 100A POWERTAB

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www.vishay.com

VS-100BGQ030HF4

Vishay Semiconductors

## High Performance Schottky Rectifier, 100 A

Anode



PowerTab<sup>®</sup>

PRODUCT SUMMARY				
Package	PowerTab <sup>®</sup>			
I <sub>F(AV)</sub>	100 A			
V <sub>R</sub>	30 V			
V <sub>F</sub> at I <sub>F</sub>	0.56 V			
I <sub>RM</sub>	460 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	9 mJ			

### **FEATURES**

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
  COMPLIANT
  COMPLIANT
- Screw mounting only
- AEC-Q101 qualified
- PowerTab<sup>®</sup> package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The VS-100BGQ030HF4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
1	Rectangular waveform	100	А			
I <sub>F(AV)</sub>	T <sub>C</sub>	106	°C			
V <sub>RRM</sub>		30	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	4500	А			
M	100 A <sub>pk</sub> (typical)	0.49	V			
V <sub>F</sub>	TJ	150	°C			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER SYMBOL		VS-100BGQ030HF4	UNITS		
Maximum DC reverse voltage V <sub>R</sub>		30	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS		
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 106 °C	100	А		
Maximum peak one cycle	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	4500	A	
non-repetitive surge current		10 ms sine or 6 ms rect. pulse		850		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 8 A, L = 1.12 mH		36	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 8		А		

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## VS-100BGQ030HF4

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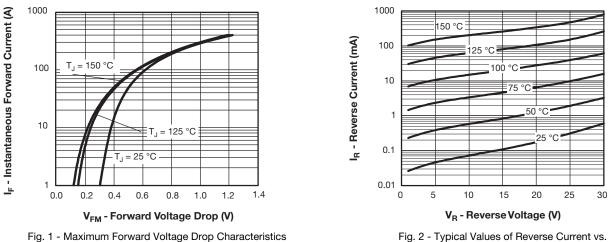
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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS
		50 A	T <sub>.1</sub> = 25 °C	0.47	0.5	v
Forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	100 A	1j=23 C	0.56	0.63	
Forward voltage drop	VFM	50 A	T.I = 150 °C	0.36	0.4	
		100 A	1j = 150°C	0.49	0.56	
	(1)	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 15 V		80	160	
Poweree leekege ourrent		T <sub>J</sub> = 150 °C, V <sub>R</sub> = 30 V		800	1100	m 4
Reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		0.6	2.4	mA
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	260	460	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal rar	38	00	pF	
Typical series inductance	Ls	Measured from tab to mounting plane			.5	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V,			V/µs	

Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and temperature range	storage	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to case RthJC DC operation		DC operation	0.50	°C/W		
Typical thermal resistar case to heatsink	nce,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.30	°C/W	
Approximate weight				5	g	
				0.18	oz.	
Mounting torque minimum				1.2 (10)	N·m	
				2.4 (20)	(lbf · in)	
Marking device			Case style PowerTab <sup>®</sup> 100BGQ030H		Q030H	



**Reverse Voltage** 

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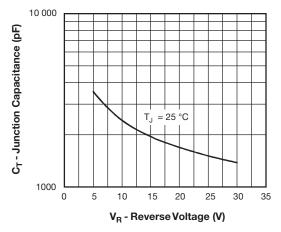


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

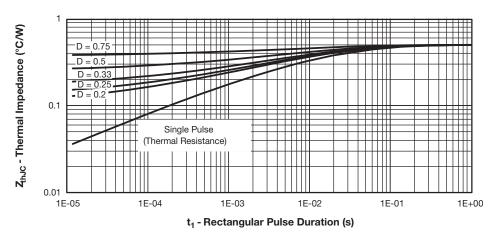
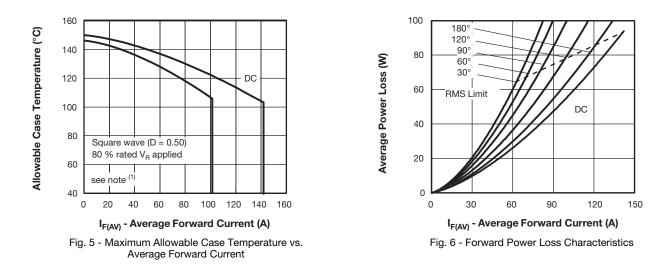


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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V	SH/				
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Surge Current (A)	10 000				
<sub>FSM</sub> - Non Repetitive Surge Current (A)	1000	<b>⊢</b> + /	At Any Rated Loa And With Rated N Following Surge		
IFSN	100 1	0 t <sub>p</sub> - S	100 Square Wave P	1000 Pulse Duratio	10 000 n (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

### ORDERING INFORMATION TABLE

### VS-100BGQ030HF4

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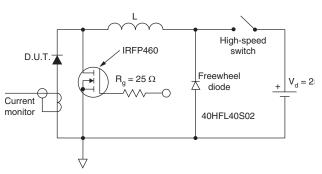


Fig. 8 - Unclamped Inductive Test Circuit

Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - $\label{eq:product} Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6); \\ Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 D); I_R at V_{R1} = 80 \% \\ rated V_R$

							-
Device code	VS-	100	BGQ	030	н	F4	
	1	2	3	4	5	6	I
	1 -		hay Sen rent rati				
	3 -	Ess	ential pa	art numb	ber	,	
	4 -	Vol	tage rati	ng (030	= 30 V)		
	5 -	H =	AEC-Q	101 qua	lified		
	6 -	- Env	/ironmer	ntal digit	:		
				complia	int and t	otally lo	ad (D

- F4 = RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-100BGQ030HF4	25	375	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			

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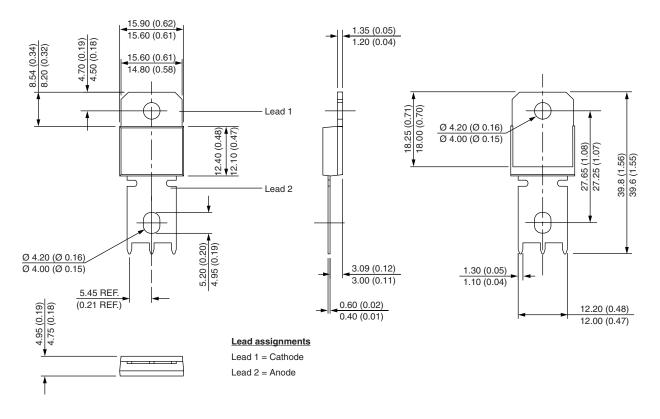
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## **Outline Dimensions**

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## **PowerTab**<sup>®</sup>

### **DIMENSIONS** in millimeters (inches)



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